

TECHNICAL DATA
DATA SHEET 4207, REV. -

Isolated Diode Array

Applications:

- High Frequency Data Lines
- RS-323 & RS-432 Networks
- LAN, Ethernet, I/O Ports
- IEC61000-4 compatible for ESD / EFT / Surge

Features:

- Protects up to 8 I/O Ports
- Isolated diodes eliminate crosstalk
- High Density Packaging
- High Breakdown Voltage; High Speed Switching (< 10 nsec)
- Low Capacitance; Low Leakage
- Hermetic Ceramic package
- TX, TXV, S level screening available

Maximum Ratings:

All ratings are at 25 °C unless otherwise noted

Characteristics	Symbol	Condition	Max.	Units
Reverse Breakdown Voltage	V_{BR}	Per diode, Pulsed @ $I_R = 5 \mu A$ $P_w = 300 \mu s \pm 50 \mu s$; duty $\leq 2\%$	75	Vdc
Continuous Forward Current	I_F	Per diode, Derate at 2.4 mA/°C above 25 °C	300	mA
Peak Surge Current	I_{FSM}	Per diode, $t_p = 8.3$ msec	500	mA
Power Dissipation	P_D	Per Junction	400	mW
Power Dissipation	P_D	Per Package, Derate at 4 mW/°C above 25 °C	500	mW
Max. Operating Temperature	T_J	-	-65 to +150	°C
Max. Storage Temperature	T_{stg}	-	-65 to +200	°C

Electrical Characteristics:

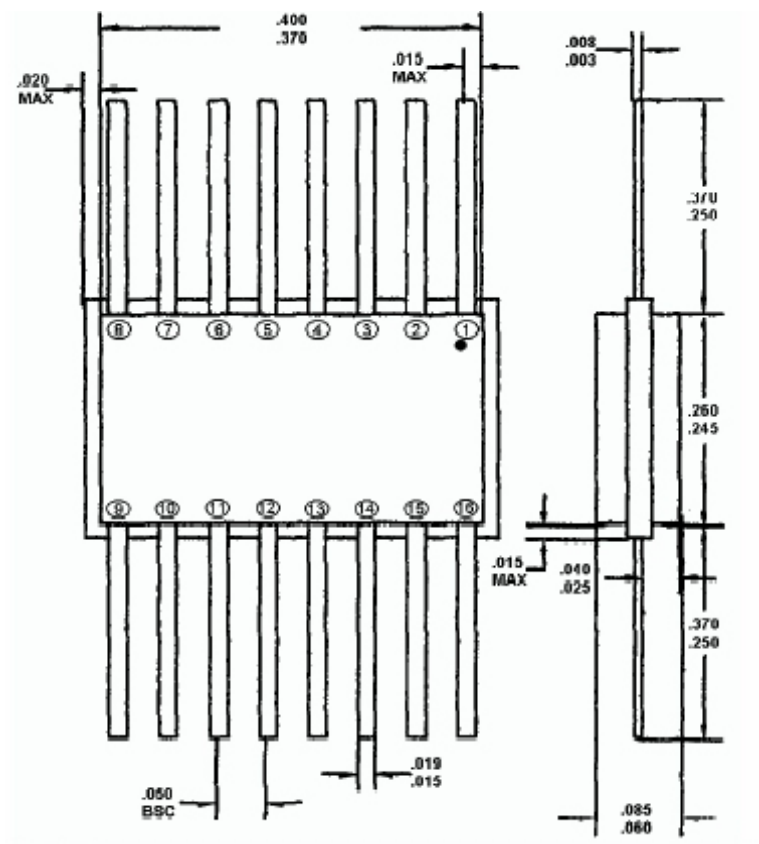
All ratings are per diode and at 25 °C unless otherwise noted

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	$I_F = 100mA$, Pulsed: $P_w = 300 \mu s$ $\pm 50 \mu s$; duty cycle $\leq 2\%$	1.00	V
Max. Reverse Current	I_{R1}	@ $V_R = 40V$	0.1	μA
	I_{R2}	@ $V_R = 20V$	25	nA
Max. Capacitance (Pin to Pin)	C_T	@ $V_R = 0V$, $F = 1MHz$	4.0	pF
Max. Forward Recovery Time	T_{FR}	$I_F = 100mA$	15	ns
Max. Reverse Recovery Time	T_{RR}	$I_F = I_R = 10mA$, $i_{RR} = 1mA$, $R_L = 100$ ohms	10	ns
Max. Forward Voltage Match	V_{F5}	$I_F = 10mA$	5	mV

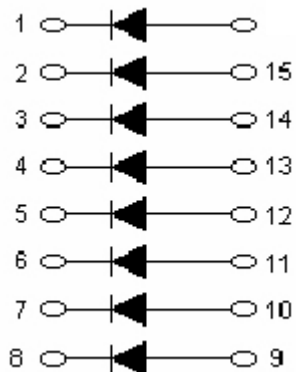
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Mechanical Dimensions: in inches / mm



Electrical Schematic



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